

EP-12 Ellipsometric Porosimeter



EP-12 System

This configuration of Ellipsometric Porosimeter has the capability of measuring 200 and 300 mm wafers. Compact in size, and the very user friendly operation, make this a perfect tool for Research and Development on porous Low-K ILD materials.

Superior Performance

The Ellipsometric Porosimetry method is more simple and more fast than PALS, SANS/SXR, or other techniques used in determining Full Porosity, Pore Size Distribution, Pore Interconnectivity and Barrier performance.

On top of this, Young Modulus of inorganic ultra low-K dielectrics can also be determined. The accuracy of pore size determination is better than 0.2 nm.

The Perfect Technology

All measurements can be carried out in a film deposited on top of a silicon wafer or any smooth solid substrate. Because a laser probe is used, small surface areas can be analyzed. Therefor EP can be used on patterned wafers as it is a non-destructive technique.

Metrology Options

The EP-12 can be configured to utilize a single wave length laser source for small surface areas, faster operation and porosity mapping, or a multi wave length source to give more information on extra characteristics like film swelling.

EP-12 Specifications

PorrEll Software

The software was developed to, if preferred, run on a remote computer if the EP-12 is hooked up to a network. It calculates open porosity, skeleton refractive index (necessary for calculation of full porosity), pore size and pore size distribution in approximately 3-5 seconds after receiving the data file from the system and loading the fitting parameters.

On top of this, it calculates multi-layer systems and therefore gives information on Barrier Layer performance and the so-called Pore Killers.



Facilities and Engineering Specifications

Wafer size:

Range of the film thickness: Pore size: Ellipsometer:

Base vacuum: Measurement temperature:

Organic adsorptives:

Nitrogen:

CD Air:

Exhaust

Electrical:

Dimensions:

System: Rack:

Net Weight:

System: Rack: 200 and 300 mm wafers and samples

> 50 nm

0.2 - 50 nm $\lambda = 6328 \text{ Å}$

λ = 3500 - 8500 Å 10⁻⁶ mBar

20°C

toluene, heptane, isopropyl alcohol

1m³/h, 1-2 Bar

2m³/h, 6-7 Bar

5m³/h Min

110/220VAC, 32A, 50/60Hz, Single Phase

1600 x 1388 x 1630 mm 600 x 600 x 1000 mm

320 kg 90 kg



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